



ELECTRONIC COPY

LABORATORY GROWN DIAMOND REPORT

LG816657989
Report verification at igi.org

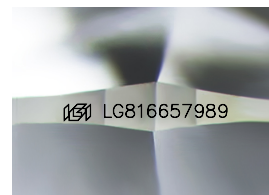
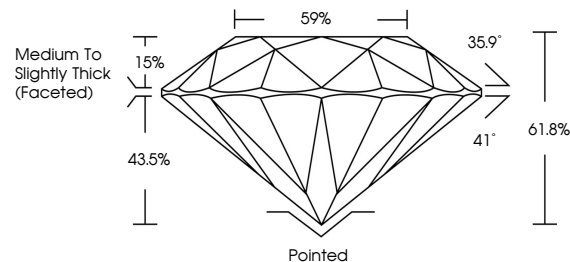
July 6, 2026	
IGI Report Number	LG816657989
Description	LABORATORY GROWN DIAMOND
Shape and Cutting Style	ROUND BRILLIANT
Measurements	8.16 - 8.19 X 5.05 MM
GRADING RESULTS	
Carat Weight	2.08 CARATS
Color Grade	F
Clarity Grade	VS 1
Cut Grade	IDEAL

ADDITIONAL GRADING INFORMATION

Polish	EXCELLENT
Symmetry	EXCELLENT
Fluorescence	NONE
Inscription(s)	 LG816657989

Comments: As Grown - No indication of post-growth treatment.
This Laboratory Grown Diamond was created by High Pressure High Temperature (HPHT) growth process.
Type II

PROPORTIONS



Sample Image Used

COLOR

D E F G H I J Faint Very Light Light

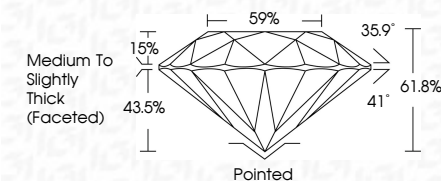
CLARITY

FL	IF	VVS ¹⁻²	VS ¹⁻²	SI ¹⁻²	I ¹⁻³
Flawless	Internally Flawless	Very Very Slightly Included	Very Slightly Included	Slightly Included	Included

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JULY 6, 2026 G Report No. L681665799 ROUND BRILLIANT	2.08 CARATS F VS 1 IDEAL 61.8% 59% Medium to Slightly Thick (Faceted)	Polished EXCELLENT EXCELLENT NONE (see L681665799)	As Grown - No indication of post-growth treatment. This Laboratory Grown Diamond was created by High Pressure High Temperature (HPHT) growth process.
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